SRM INSTITUTE OF SCIENCE AND TECHNOLOGY, RAMAPURAM CAMPUS, CHENNAI

DEPARTMENT OF PHYSICS

QUESTION BANK - I YEAR B.Tech.

18PYB103J- SEMICONDUCTOR PHYSICS

UNIT 3

PART A-ONE MARK QUESTIONS

 is the proophotons. (A) Radiative transitio (B) Non-radiative transitio (C) Absorption (D) Radiation 	
kent open is called	ge generated across the terminals of solar cell when they are Narimum Voltage \rightarrow Open circuit Minimum Voltage \rightarrow Short circuit. $V = \frac{nkT}{q} \ln(1 + \frac{T}{4} L_{s})$ $V = 0$
	s is in which the electron-hole pairs are created and recombined Optical process 1) Luminescence - e/e+ created 2) Photoluminescence - e/e+ created by light 3) Cathodluminescence - e/e+ created by e- bombardment 4) Electroluminescence - recombination by injection with pn-junction
 4. The average velocity presence of electric field (A) Relaxation time (B) Drift velocity (C) Collision time (D) Diffusion current 	y acquired by the electrons in a particular direction during the

	5. The photons of energy value that of the band gap values do not get absorbed in photovoltaic cell.(A) Greater than
	(B) Less than
	(C) Nearly equal than
	(D) Zero
	6 is the process where the excess energy due to recombination is usually
	imported to phonons and dissipated as heat.
	(A) Radiative transition
	(B) Non-radiative transition
	(C) absorption
	(D) Radiation.
	7. The radiative recombination of electron-hole pair created by injection of photons is
	called
	(A) Photoluminescence
	(B) Photon emission
	(C) Phonon emission
	(D) Radiation
	8. The maximum current flows in solar cell when its P-side & N-side terminal are
	shorted, such a current is called
	(A) Drift current
	(B) Diffuse current
	(C) Short-circuit current
La.	(D) Alternative current
	9. The ratio between E _g and charge of electron in photovoltaic cell is called
	(A) Current loss
	(B) Voltage loss
	(C) loss due to metal
	(D) Optical loss.
W	(2) 56.03
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0. The given diagram represents A)Spontaneous emission E2 S) Stimulated emission	
C) Absorption process	
D) Temperature inversion E1	
1. Which of the following is responsible for electrical conduction in metal? A) Electrons B) Protons C) Neutrons D) Positrons	
2. The given diagram represents	
3. The does not require any external energy for process to take place. A) Stimulated emission B) Spontaneous emission C) Stimulated absorption D) Stimulated radiation.	
4. The light amplification is achieved by from an atomic or molecular system. A) Spontaneous emission B) Stimulated emission C) Time inversion Light amplification	η
5 is the process of radiative recombination of electron–hole pairs created by lectron bombardment. A) Photoluminescence B) photon emission C) Phonon emission D) Cathodoluminescence	
6. The open circuit voltage of a solar cell increases with A) Increase in bandgap B) Decrease in band gap C) Increase of in holes D) Decrease in holes	

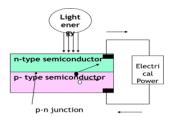
- 17. The current density is directly proportional to the ______.
- (A) Rest mass of electron

(B) Applied electric field

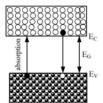
- (C) density of core electron
- (D) Collision time.



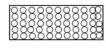
- 18. The given diagram represents effect.
- (A) Photovoltaic effect
- (B) Compton effect
- (C) Raman effect
- (D) Zeeman Effect.



- 19. The ratio of the maximum power that can be extracted from a solar cell to the ideal power is called ____.
- (A) Short circuit voltage
- (B) Open circuit voltage
- (C) Fill factor
- (D) Drift Voltage
- 20. The sun light can be converted to electricity due to the _____.
 - (A) Photovoltaic effect
 - (B) Compton effect
 - (C) Raman effect
 - (D) Zeeman Effect.
 - 21. Which one of the following is related to the diagram?
 - (A) Band to band transition
 - (B) Impurity to band transition
 - (C) Free carrier Transition
 - (D) Photonic transition

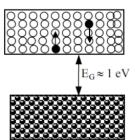


- 22. Which one of the following is related to the diagram?
- (A) Band to band transition
- (B) Impurity to band transition
- (C) Free carrier Transition
- (D) Photonic transition





- 23. Which one of the following is not a postulate of Classical free electron theory?
- (A) The valence electrons are freely moving about the whole volume of the metals
- (B) The energy levels of the electrons moving inside the metal are discrete.
- (C) The free electrons collide with each other positive ions
- (D) When the electric field is applied all the valence electrons a drifted
- 24. Which one of the following is related to the diagram?
- (A) Band to band transition
- (B) Impurity to band transition
- (C) Free carrier Transition
- (D) Photonic transition



- 25. Illustrate the properties of Photoluminescence
- (I) The Principle of this method is based on the absorption of ultraviolet light or visible light by chemical compounds, which results in the production of distinct spectral Spectroscopy is based on the interaction between light and matter.
- (II) It is a process in which a molecule absorbs a photon in the visible region, exciting one of its electrons to a higher electronic excited state, and then radiates a photon as the electron returns to a lower energy state.
- (III) This method is routinely used in **analytical chemistry** for the quantitative determination of different analytes, such as transition metal ions, highly conjugated organic compounds, and biological macromolecules.
- (IV) It is the spontaneous emission of light from a material following optical excitation. It is a powerful technique to probe discrete energy levels and to extract valuable information about semiconductor sample composition, quantum well thickness or quantum dot sample mono dispersity.
- (A) All the four Incorrect
- (B) Both II and III correct
- (C) Both III and I correct
- (D) Both II and IV correct
- 26. The direct band to band absorption and emission can take place only at frequencies for which photon energy _____.
- (A) $h\gamma > E_{\alpha}$
- (B) $h\gamma < E_g$
- (C) $h\gamma = E_g$
- (D) hy = 0

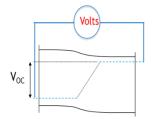
27. The ratio between spontaneous and stimulated (A) Lorenz number (B) Lorentz coefficient (C) Absorption coefficient (D) Einstein's coefficient	emission coefficients is called
 28. Analyse the device Photovoltaic Cell I) The single photovoltaic cell constitute the <i>n-type</i> layer type layer. (II) This is an electrical device that converts the energy of electron of all optoelectronic devices is based electron hole pairs. (IV) These are the class of vacuum tubes, and more speare extremely sensitive detectors of light. (A) Both I and II correct (B) Both I and III correct (C) Both II and IV correct (D) Both I and II correct 	ilight into electricity. on creation or annihilation of Statement
29. Analyse recombination process	
(I) simplest way to achieve this phenomenon is to irradia	te the semiconductor
(II) Recombination maybe radiative or non radiative.	
(III) Pair formation essentially involves raising an electron band to conduction band leaving hole behind in valence I	•
(IV) The energy levels of the electrons moving inside the	e metal are discrete. Atteast by
 (A) Both I and IV correct (B) Both I, II and III correct (C) Both II and IV correct (D) Both III and IV correct 	hewor laws WKT -they are Continuous.
30. Efficiency of single crystalline Silicone is about (A) 14 – 17 (B) 1-7 (C) 13 – 15 (D) 5 - 7	

TRUE

- 31. Which one of the following is not a drawback of Classical free electron theory?
- (I) It could not explain photoelectric effect and Compton effect.
- (II) It verifies ohms law.
- (III) Electrical conductivity of semiconductors and insulators could not explain.
- (IV) Ferromagnetism could not explain by this theory.
- (a) Both I and III correct
- (b) All the four Incorrect
- (c) II correct
- (d) Both I and IV correct
- 32. The average velocity acquired by the free electrons of a metal in aparticular direction by the application of electric field equal to -----.
- (I) eE_T/m
- (II) eET m
- (III) eE / m
- (IV) eT / m



- 33. Which one of the following is related to the diagram?
- (A) Open circuit voltage
- (B) Short circuit voltage
- (C) Short circuit current
- (D) Open circuit Current



34. Which one of the following is related to this expression?

$$W_{abs} = \frac{2\pi}{\hbar} |\langle f | H_{int} | i \rangle|^2 \delta(E_f - E_i - \hbar \omega)$$

- (A) Joint density of states
- (B) Fermi's Golden Rule
- (C) Energy density
- (D) Fermi Energy
- 35. Fill factor of PV cell equal to ------
- (A) (I $_{mp}$) / (I $_{SC}$. V_{OC})
- (B) (I $_{mp}$.V $_{mp}$) / (I $_{SC}$. V $_{OC}$)
- $(C) (V_{mp}) / (I_{SC})$
- (D) $(I_{mp}.V_{mp}) / (V_{OC})$
- 36. Calculate the electrical resistivity of sodium at 0° C. It has 25.33 x 10^{27} unit volume and has a mean free time of 3.2 x 10^{14} s.

$$P = ?$$

$$-2 = ML^{2}TT$$







(A) $4.532 \times 10^{-36} \Omega \text{ m}$ (B) $5.431 \times 10^{-36} \Omega \text{ m}$ (c) $6.81 \times 10^{-36} \Omega \text{ m}$ (D) $3.12 \times 10^{-36} \Omega \text{ m}$
37. Efficiency of Amorphous Silicone is about (A) 14 – 17 (B) 1-7 (C) 13 – 15 (D) 5 - 7
(5) 5 - 1
38. The spectral region where the material changes from being relatively transparent to strongly absorbing is known as
(A) Absorbing edge
(B) Conduction edge
(C) Valance edge
(D) Annihilation edge
39. In stimulated emission, the state at which the life time of atoms is extended is
(A) Metastable state
(B) Stable state
(C) Excited state
(D) Ground state
 40. The absorption coefficient of semiconducting materials strongly depends on the